#### LOW NOISE AMPLIFIER/MIXER



#### **Features**

RFM

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- Single 3V to 6.5V Power Supply
- 500MHz to 1900MHz Operation
- 25dB Small Signal Gain
- 2.5dB Cascaded Noise Figure
- 8.5 mA DC Current Consumption
- -8dBm Input IP<sub>3</sub>

#### **Applications**

- UHF Digital and Analog Receivers
- Digital Communication Systems
- Spread-Spectrum Communication Systems
- Commercial and Consumer Systems
- Portable Battery-Powered Equipment
- General Purpose Frequency Conversion



## **Product Description**

The RF2411 is a monolithic integrated UHF receiver front-end. The IC contains all of the required components to implement the RF functions of the receiver except for the passive filtering and LO generation. It contains an LNA (low-noise amplifier), a second RF amplifier, and a balanced mixer which can drive a single-ended or balanced load. The output of the LNA is made available as a pin to permit the insertion of a bandpass filter between the LNA and the RF/Mixer section. The LNA output is buffered to permit a wide range of choices for the interstage filter without altering the VSWR or noise figure at the LNA input and to provide high isolation from the LO to the input port. The LNA section may be disabled to conserve power.

#### **Ordering Information**

RF2411	Low Noise Amplifier/Mixer
RF2411 PCBA-L	Fully Assembled Evaluation Board (850MHz)
RF2411 PCBA-H	Fully Assembled Evaluation Board (1800MHz)

#### **Optimum Technology Matching® Applied**

🗹 GaAs HBT	□ SiGe BiCMOS	GaAs pHEMT	🗌 GaN HEMT
GaAs MESFET	Si BiCMOS	🗌 Si CMOS	
InGaP HBT	SiGe HBT	🗌 Si BJT	

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#### **Absolute Maximum Ratings**

Parameter	Rating	Unit
Supply Voltage	-0.5 to 7.0	V <sub>DC</sub>
Input LO and RF Levels	+6	dBm
Ambient Operating Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	°C



Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective2002/95/EC (at time of this document revision).

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	Specification					
Parameter (850 MHz)	Min.	Тур.	Max.	Unit	Condition	
Overall					T = 25 °C, $V_{CC}$ =5V, RF=850MHz, LO=0dBm, IF=50MHz, Application Schematic 2 configura- tion	
RF Frequency Range		500 to 1900		MHz		
IF Frequency Range		DC to 150		MHz		
Cascade Gain		27		dB	IF=10MHz	
	21	25	29		IF=50MHz	
		20			IF=150MHz	
Cascade IP3		-8		dBm	Referenced to the input	
Cascade Noise Figure		2.4	7	dB	Single sideband, IF=10MHz	
		2.4		, The second sec	Single sideband, IF=50MHz	
		3.4	$\langle \rangle$	Ť	Single sideband, IF=150MHz	
First Section (LNA)						
Noise Figure		1.6		dB		
Input VSWR		1.5:1				
Input IP3		-3.5		dBm		
Gain		14		dB		
Reverse Isolation		30		dB		
Output VSWR		2.0:1				
Second Section (RF Amp,						
Mixer, IF1)						
Noise Figure		11.0		dB	Single Sideband	
Input VSWR		2.0:1				
Input IP3		+6		dBm		
Conversion Gain		11		dB		
Output Impedance		4		kΩ	Open Collector	
LO Input						
LO Level		-6 to +6		dBm		
LO to RF Rejection		30		dB		
LO to IF Rejection		30		dB		
LO Input VSWR		1.5:1				
Power Supply						
Voltage		3 to 6.5		V		
Current Consumption		8		mA	V <sub>CC</sub> =3.0V	
		20		mA	V <sub>CC</sub> =5.0V	





Deverseter (1800 MU-)	Specification		Unit	Condition			
Parameter (1800MHz)	Min.	Тур.	Max.	Unit	Condition		
Overall					T=25°C, V <sub>CC</sub> =5V, RF=1800MHz,		
Overall					LO=OdBm, IF=50MHz, Application Schematic 2 configuration		
RF Frequency Range		500 to 1900		MHz			
IF Frequency Range		DC to 100		MHz			
Cascade Gain		22		dB	IF=10MHz		
		21			IF=50MHz		
		17			IF=150MHz		
Cascade IP3		-7		dBm	Referenced to the input		
Cascade Noise Figure		4.0		dB	Single sideband, IF=10MHz		
		4.0			Single sideband, IF=50 MHz		
		4.8			Single sideband, IF=150MHz		
First Section (LNA)							
Noise Figure		2.6		dB			
Input VSWR		1.2:1					
Input IP3		-3.5		dBm			
Gain		10		dB			
Reverse Isolation		25		dB			
Output VSWR		1.5:1					
Second Section (RF Amp,							
Mixer, IF1)							
Noise Figure		10.0		dB	Single Sideband		
Input VSWR		2.0:1					
Input IP3		+3		dBm			
Conversion Gain		11		dB			
Output Impedance		4		kΩ	Open Collector		
LO Input							
LO Level		-6 to +6		dBm			
LO to RF Rejection		30		dB			
LO to IF Rejection		30		dB			
LO Input VSWR		1.2:1					

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Pin	Function	Description	Interface Schematic
1	LNA IN	This pin is NOT internally DC-blocked. An external blocking capacitor must be provided if the pin is connected to a device with a DC path. A value of 100 pF is recommended for 900 MHz and 22 pF for 1800 MHz.	
2	GND	Ground connection. For best performance, keep traces physically short and connect immediately to ground plane.	
3	GND	Same as pin 2.	
4	GND	Same as pin 2.	
5	GND	Same as pin 2.	G
6	IF OUT+	Balanced open collector output of the mixer. External bias needs to be supplied to this pin. This can be done with a resistor to $V_{CC}$ (see application schematic, "1800MHz, Balanced Resistor Output Matching"), with a balun (see application schematic, "1800MHz, Output Matching with Balun") or when used in a single-ended configuration (see application schematic, "1800MHz, Single-Ended Resistive Output Matching"). When using a resistor to $V_{CC}$ the resistor value will set the output impedance. Typical values for this resistor are $200\Omega$ to $1k\Omega$ . A shunt inductor/capacitor resonator to $V_{CC}$ is needed to maintain proper DC voltage at the mixer. At low resistor values the resonator may be omitted at the expense of gain, output power and IP3. To obtain maximum gain and output power a balun as shown in application schematics "1800MHz, Output Matching with Balun" and "850MHz, Output Matching with Balun" and a GdB gain improvement over the plain single ended configuration.	O IF OUT+ O IF OUT-
7	IF OUT-	Same as pin 6 except complementary output.	See pin 6.
8	LO IN	$50\Omega$ mixer LO input. This pin has an internal pull-up resistor to $V_{CC}$ and is not DC-blocked. An external blocking capacitor must be provided if the pin is connected to a device with a DC path. A value of 100 pF is recommended for 900MHz and 22 pF for 1800MHz.	
9	RF IN+	Balanced mixer RF Input port. This pin is NOT internally DC-blocked. An external blocking capacitor must be provided if the pin is connected to a device with a DC path. A value of 100 pF is recommended for 900MHz and 22 pF for 1800MHz. Matching is required; see the applications schematics. To minimize the noise figure it is recommended to have a bandpass filter before this input. This will prevent noise at the image frequency from being converted to the IF.	RF IN+
10	RF IN-	Same as pin 9 except complementary input.	See pin 9.
11	VCC2	Supply voltage for the mixer bias circuits.	
12	VCC1	Supply Voltage for the LNA only. A 47 pF external bypass capacitor is required and an optional $0.01 \mu F$ will be required if no other low frequency bypass capacitors are nearby. The trace length between the pin and the bypass capacitors should be minimized. The ground side of the bypass capacitors should connect immediately to ground plane.	





Pin	Function	Description	Interface Schematic
13	NC	No connection.	
14	LNA OUT	$50\Omega$ output. An external DC blocking capacitor is required when this pin is connected to a DC path.	









**Application Schematic** 850 MHz, Output Matching with Balun 5 0 Ω I m a g e 100 pF LNA RFIN O--11-14 1 13  $\simeq$ Vcc 12 11 100 n F 300 p F 10 5 MIXER IF OUT O 9 6 100 pl RFAMP 8 7 Г 100 n l 100 pF -O LO IN 100 **Application Schematic** 1800MHz, Output Matching with Balun 5 0 Ω 22 pF LNA REIN O -1 F 14 13  $\approx$ Vcc 12 11 100 n F 300 pF 10 5 22 p F MIXER 2.7 nH IF OUT 6 9 RFAM 7 8 22 p F -O LO IN 22 p F











# **Evaluation Board Schematic**







Evaluation Board Schematic Mixer Tuned for 1800MHz

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#### **LO Input RF Input (single ended)** Swp Max 3.01GHz 1.0 Swp Max 1.0 8.0 8.0 0.0 3.01GHz Ò Vcc=2.7V - Vcc=2.7V -B-Vcc=3.6V 3<u>0</u> 3.Ò 0 0 -**B-** Vcc=3.6V ✤ Vcc=5.0V 4.0 4.0 ✤ Vcc=5.0V Vcc=6.0V 5.0 5.0 - Vcc=6.0V <u>ج:</u> 6<sup>:</sup>5 10MHZ 10.0 10.0 10.01 0.8 ¢. 0.2 0.2 3.0 400 4.0 9.0 þ0 C 9.4 0.6 ф Л Ö 0 0 0 ć 10MHZ 3GHZ 0.01 S 3GHZ 3GHZ 🔍 -0.2 .0.2 6 *0*ۍ С 0.4 0.4 3GHZ ,0 ,0 00 Swp Min -0.8 ò. Q Swp Min 0.01GHz 0.01GHz **IF Output** Swp Max 1.0 8.0 3.01GHz ċ ĉ - Vcc=2.7V 3.0) Ċ 4.0 ← Vcc=5.0V 5.0 Vcc=6.0V 12:0 10.0 H A 10,0 2 o. 6 7. 0 0 Ċ. ö ¢. ć 3GHZ 10MHZ 0.0 Swp Min 0.01GHz





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### **RoHS\* Banned Material Content**

RoHS Compliant:	Yes
Package total weight in grams (g):	0.127
Compliance Date Code:	0531
Bill of Materials Revision:	-
Pb Free Category:	e3

Bill of Materials	Parts Per Million (PPM)					
	Pb	Cd	Hg	Cr VI	PBB	PBDE
Die	0	0	0	0	0	0
Molding Compound	0	0	0	0	0	0
Lead Frame	0	0	0	0	0	0
Die Attach Epoxy	0	0	0	0	0	0
Wire	0	0	0	0	0	0
Solder Plating	0	0	0	0	0	0

This RoHS banned material content declaration was prepared solely on information, including analytical data, provided to RFMD by its suppliers, and applies to the Bill of Materials (BOM) revision noted

\* DIRECTIVE 2002/95/EC OF THE EUROPEAN PARLIAMENT AND OF THE COUNCIL of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment

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